

SPACE TRANSPORTATION

MEMSRAD – MEMS Sensitivity to Space Radiation

C. OUDEA (Astrium-Space Transportation)

O. VENDIER (Thales Alenia Space)

R. GAILLARD & P. POIROT (Infoduc)

27th January 2009 at PSI, Switzerland

All the space you need

ESA – CNES QCA Day at PSI – 27-28/01/2009

C. OUDEA – Astrium ST



Outline

- Introduction
- MEMSRAD Goal
- MEMS Selection Criteria
- Selected MEMS Presentations
 - Accelerometers
 - RF MEMS
- Preliminary Results
 - Accelerometers
 - RF MEMS
- Conclusions

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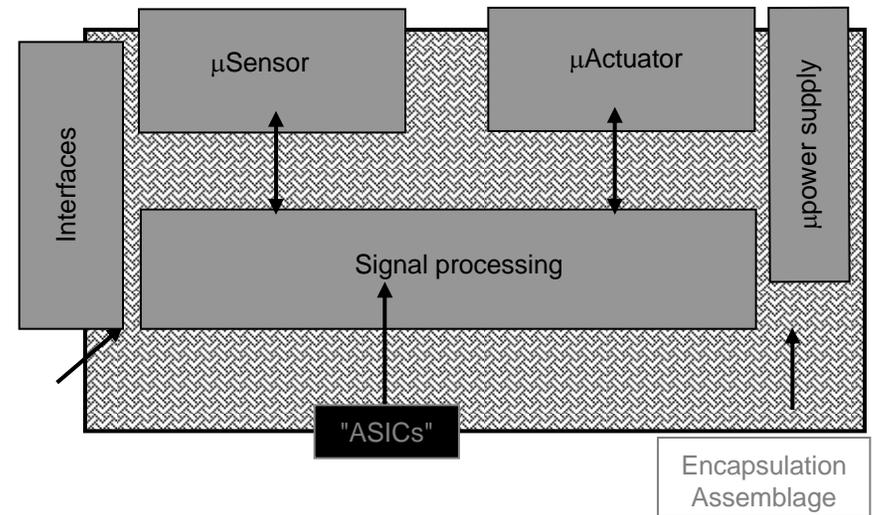
Introduction (1/3)

- **MEMSRAD Contract**
 - ESA/ESTEC Contract n°: 20293/06/NL/CP
 - Duration : 24 months
- **Members of Consortium**
 - EADS - Astrium Space Transportation : Prime
 - Sub Contractors:
 - EADS Innovative Works, Ottobrun (Ge)
 - Thales Alenia Space, Toulouse (Fr)
 - Infoduc (Fr)

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Introduction (2/3)

- MEMS :
 - A system with atleast 2 functions:
 - Sensor / Actuator + Signal treatment
 - Manufactured / assembled:
 - On a single wafer: monolithics,
 - With few wafers: hybride



USA

MEMS : Micro-ElectroMechanical Systems

MOEMS : Micro-OptoElectroMechanical Systems

JAPON

Micromachines

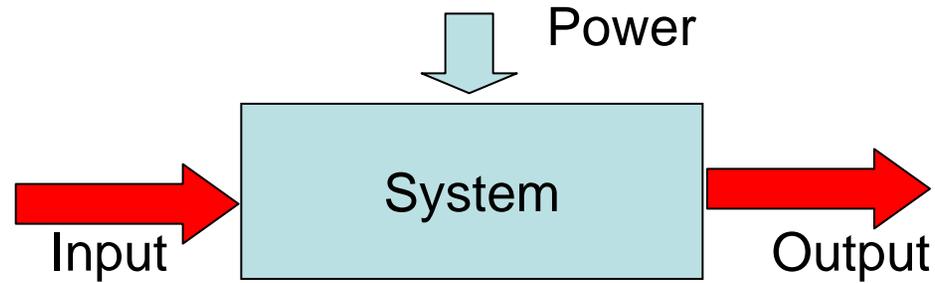
EUROPE

Microsystèmes

MST(MicroSystems Technology)

Introduction (3/3)

MEMS and Microelectronics



System	Input	Output
Microelectronic	Current, Voltage, frequency	Current, Voltage, frequency
MEMS Sensor	<i>Acceleration, Temperature, Rotation Pressure</i>	Current, Voltage, frequency
MEMS Actuator	Current, Voltage	<i>Contact, Rotation, Translation,...</i>

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MEMSRAD GOAL (1/2)

Radiation Guidelines

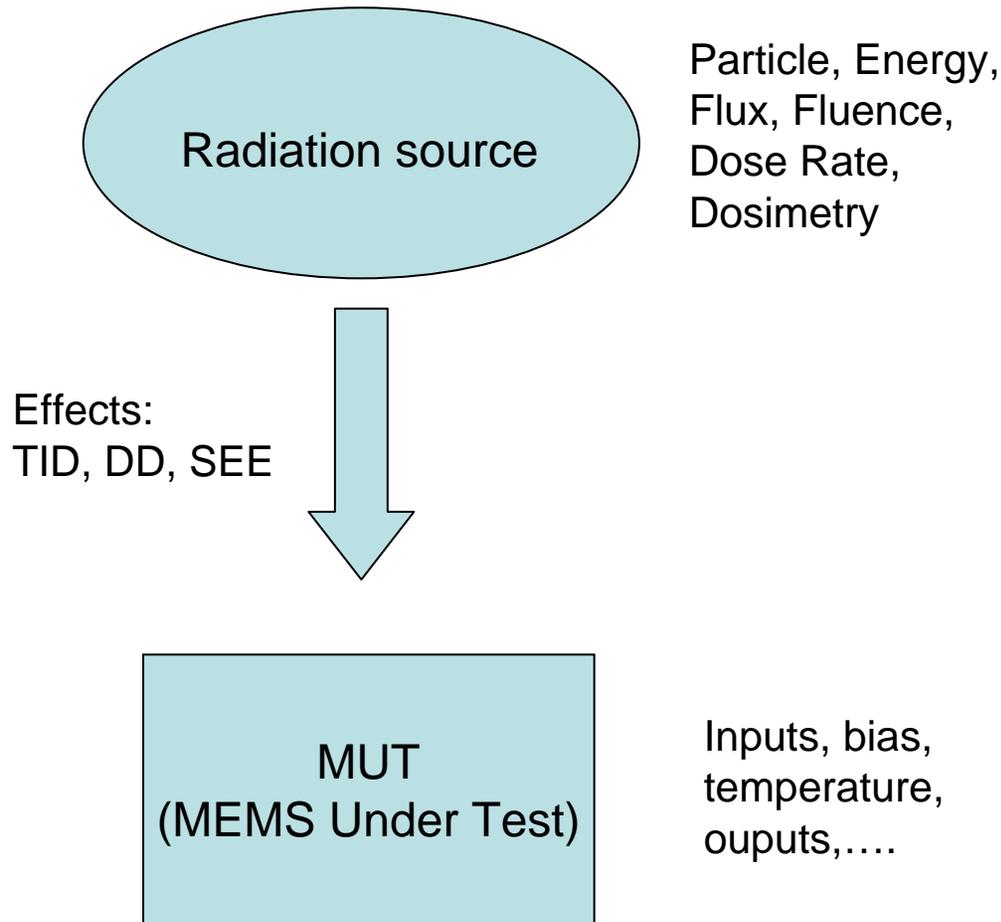
■ Purpose of this work

- Prepare guidelines for Radiation Testing of MEMS
- Help to perform characterization of MEMS and obtain meaningful results.
- Allow different « End-Users » to share and compare results obtained with a common testing procedure.

■ Methodology

- Analysis of existing Radiation Testing Guidelines and Methods
- Identification and Classification of MEMS
- Identify important points to adapt or modify the guidelines
 - a priori
 - after performing tests on MEMS
- Consider other Guidelines applied to MEMS:
 - Reliability evaluation
 - Specific testing methods related to the specific function

MEMSRAD GOAL (2/2) MEMS sensitivity to space RADIation



- ### Radiation Tests Facilities:
- Total dose: Co60 (ESA/ESTEC)
 - Single Event Effects
 - Heavy ions (UCL)
 - Protons (PSI)
 - Displacement Damage
 - Protons PSI (E=150MeV)

Selection criteria for MEMS (1/2)

Criteria:

- European source
- Matured Technology,
- Matured Product with high TRL for other applications
- Industrial production (avoid prototypes!)
- Availability
- Manufacturer cooperation (highly recommended)
 - Willingness to work for space applications
 - Providing samples
 - Providing sufficient technical informations (not a « black box »)
 - Possibility to exchange technical data's during the testing
 - Short & mid term participation
 - to improve the product, if necessary
 - appropriate packaging, redesign an ASIC (rad tolerant/hardened), etc.

Selection criteria for MEMS (2/2)

Criteria:

- Potential Space applications
- Past radiation experiences (internal, external)

- Expected radiation effects
 - TID (Total Induced Dose)
 - SEE (Single Event Effects)
 - DD (Displacement Damage)

- Availability of 2 type of MEMS at same time for radiation testing

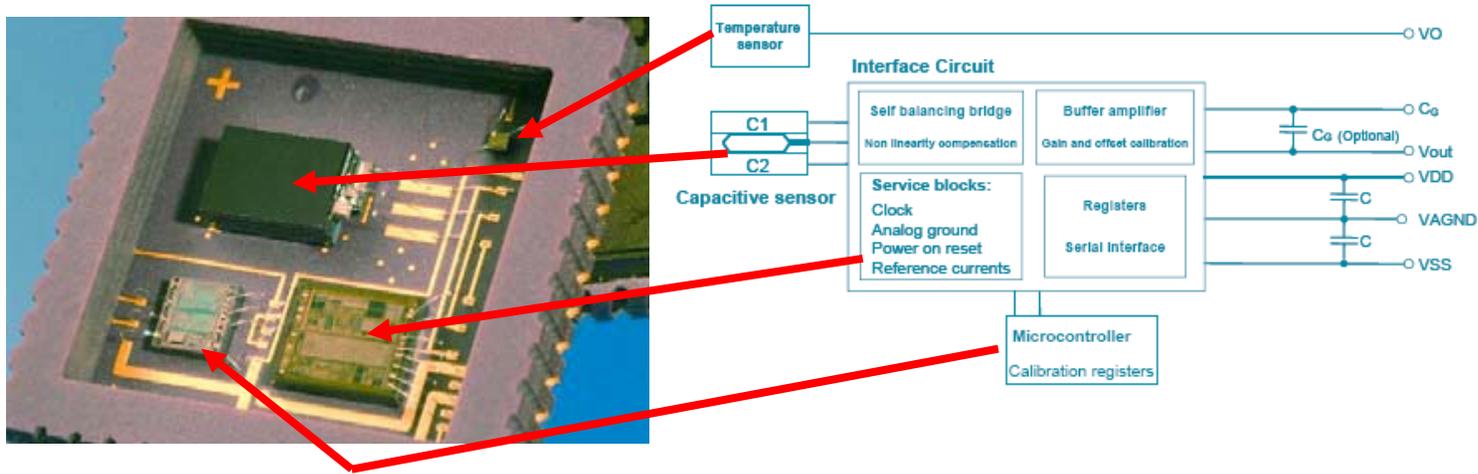
- Easy to test:
 - Before and after different radiation testing
 - Possibility to do the « on-line » parameters during different radiation testing

- Possibility to separate the contributions from:
 - Sensing element
 - Electronic circuits

- To allow the improvements in our « Radiation Guidelines » at the end of testing

SELECTED MEMS Presentation (1/2)

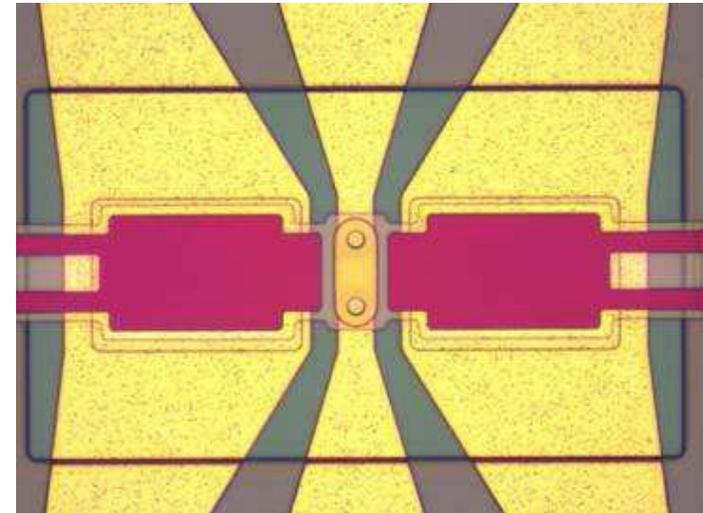
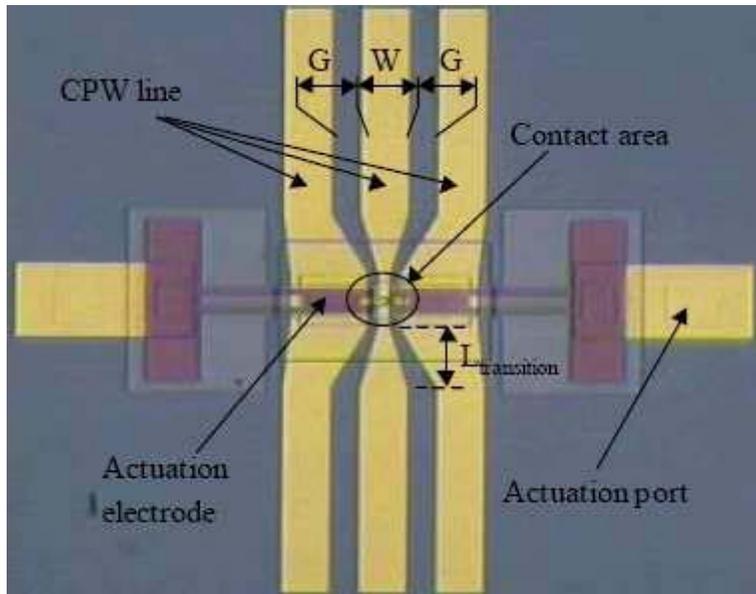
MEMS Type 1: Colibrys Accelerometer description



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SELECTED MEMS Presentation (2/2)

MEMS Type 2: RF MEMS from LETI-CEA



Ohmic contact switch

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Preliminary Results

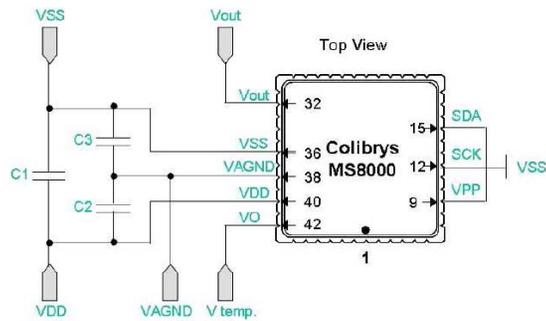
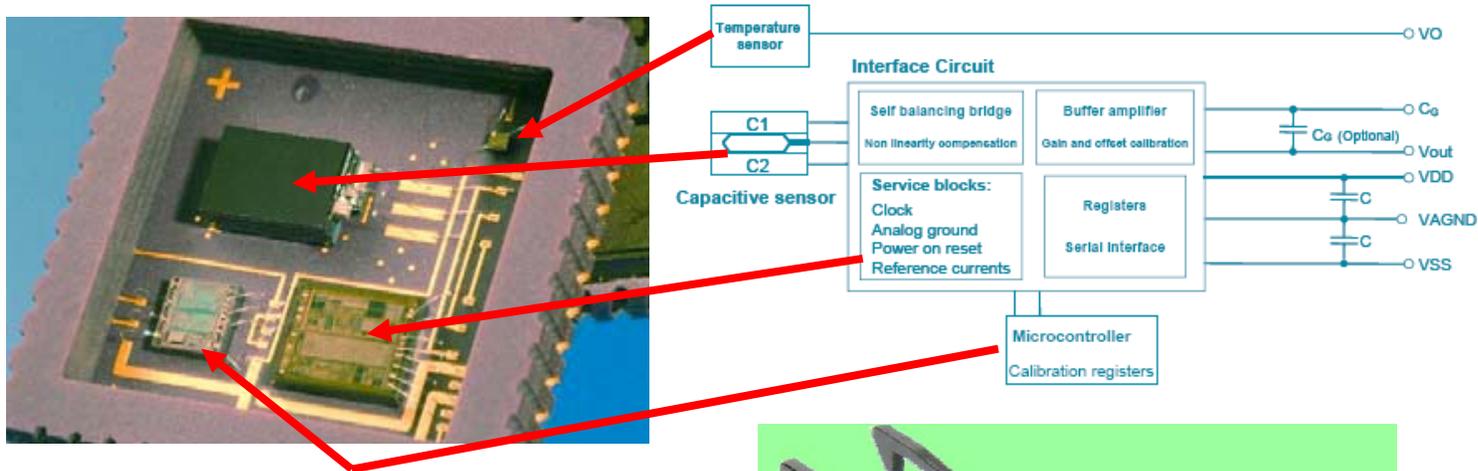
Test preparation: Initial measurements

- Obtain devices and verify the stability of the process
- Define or use standards on measurement procedures
 - Verify the homogeneity of a given lot
 - Verify the stability of the parameters:(sensitivity to temperature, humidity)
 - Verify the possibility to test the devices in the irradiation facility (package, thermal dissipation, mechanical state)
- Ex: Special adaptation:
 - Test Jig RF-MEMS
 - Accelerometer positioning

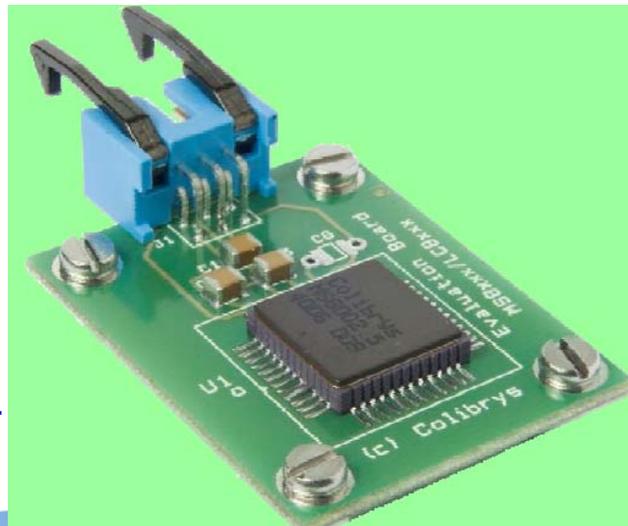
Preliminary Results

Accelerometers

DUT (Accelerometer) description:



$C1=C2=C3=1\mu F$



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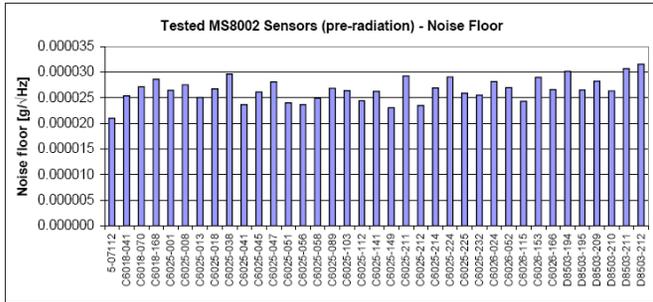
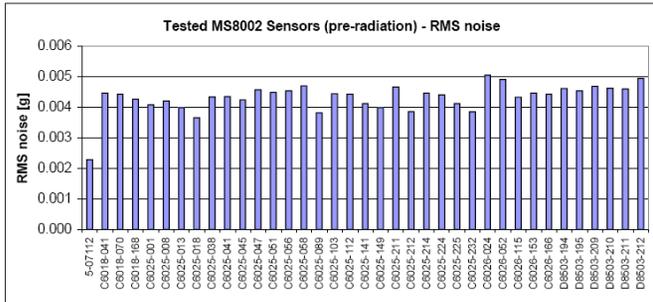
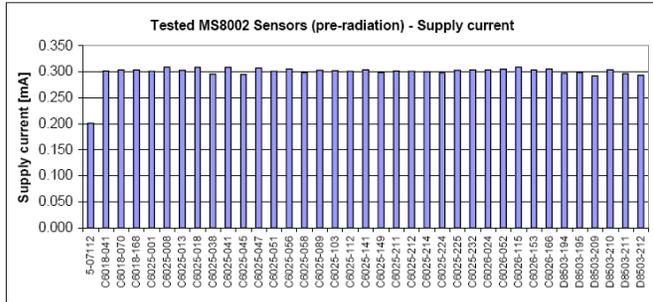
Preliminary Results

Accelerometers

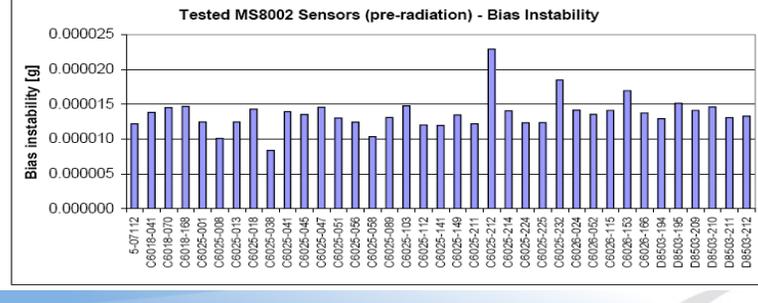
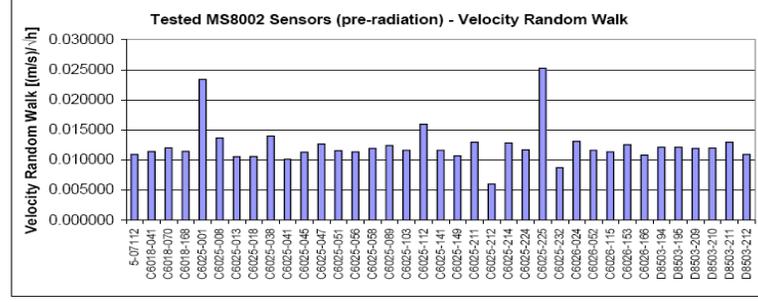
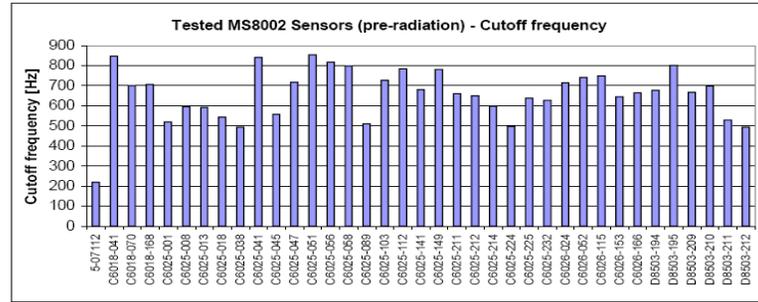
Pre irradiation measurements

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MS8002 Test Results (pre-radiation)



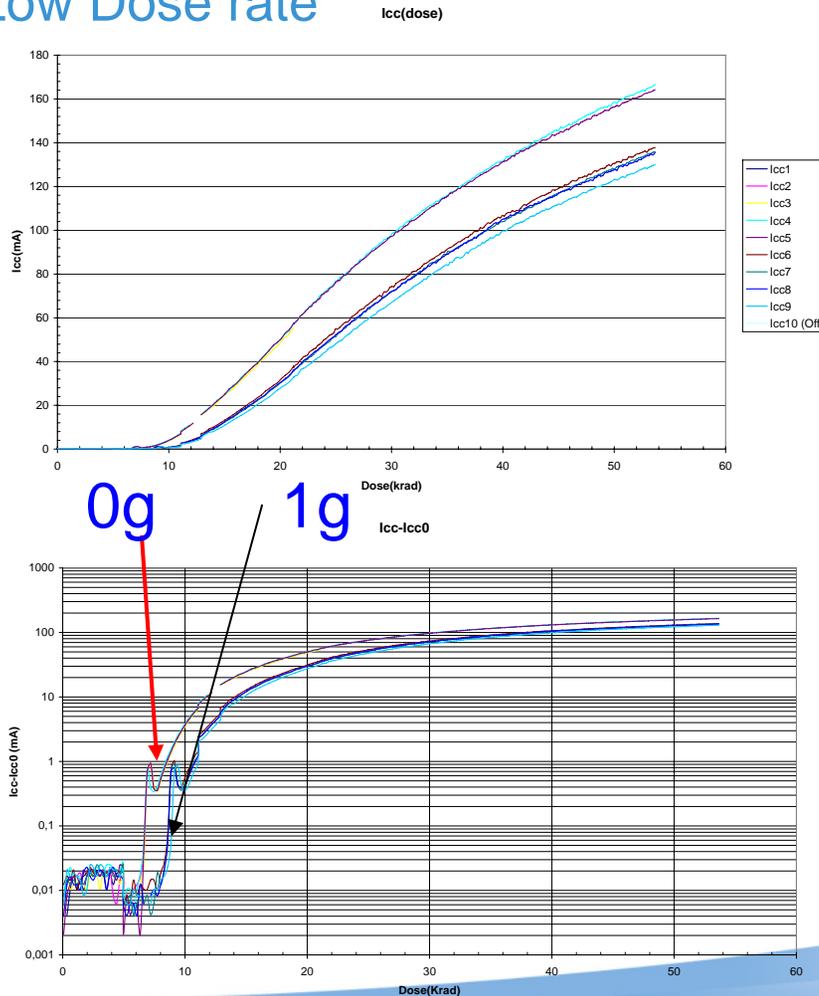
MS8002 Test Results (pre-radiation)



Preliminary Results

Accelerometers TID

On line measurements Power supply Current Low Dose rate



- Strong increase of power supply current

Log scale:
Increase begins at 6-8 krad
Threshold related to input: 1g or 0g

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Preliminary Results

Accelerometers – Heavy Ions

Heavy ion test results

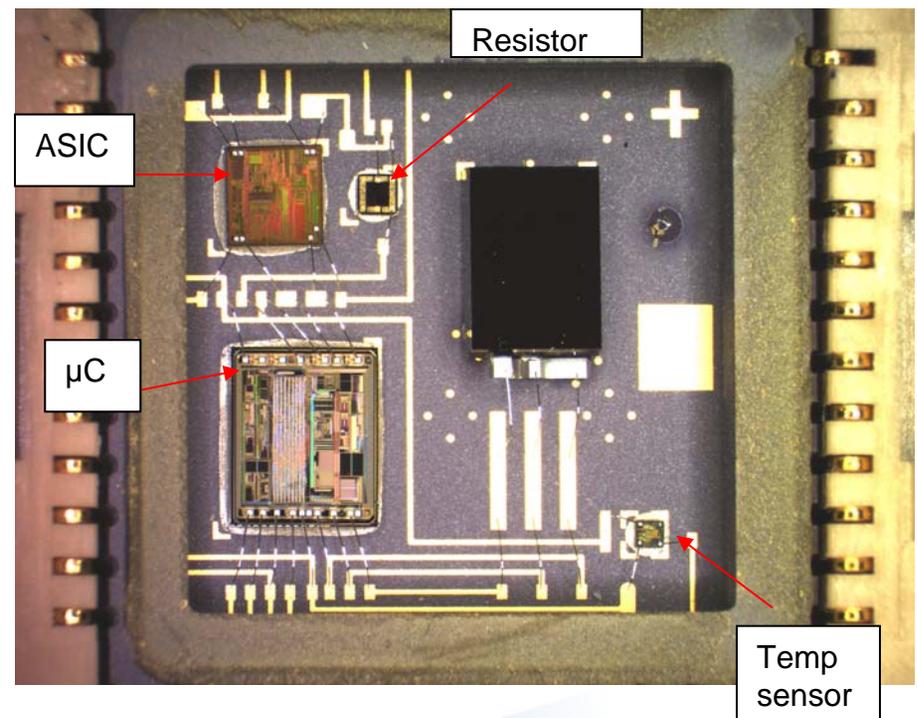
- Heavy ion range: a limitation to test sensors
- System response to heavy ions:
 - Understand the system behaviour: electrical response, calibrations, reset
 - Example of SET

Preliminary Results

Accelerometers - Heavy Ions

Separation of the contributions

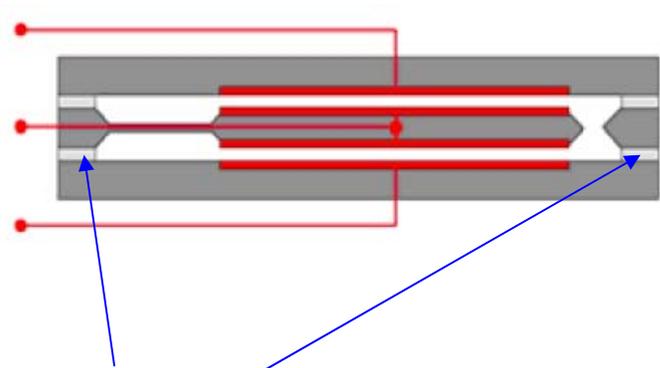
- Irradiation of one part at a time
 - Acceleration Sensor
 - Temperature sensor
 - ASIC +resistor network
 - Microcontroller (μC)
- Difficult to verify if ions do not reach other parts



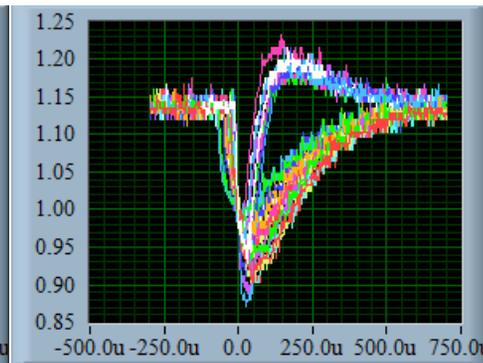
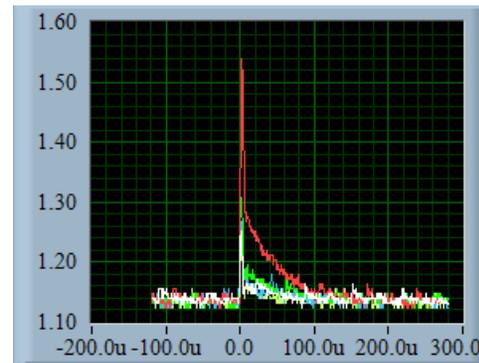
Preliminary Results Accelerometer - Heavy Ions

Tests on acceleration sensor : at 0g

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OXIDE



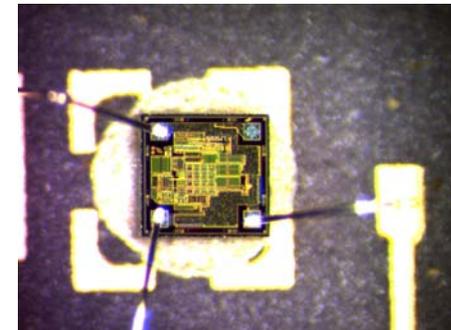
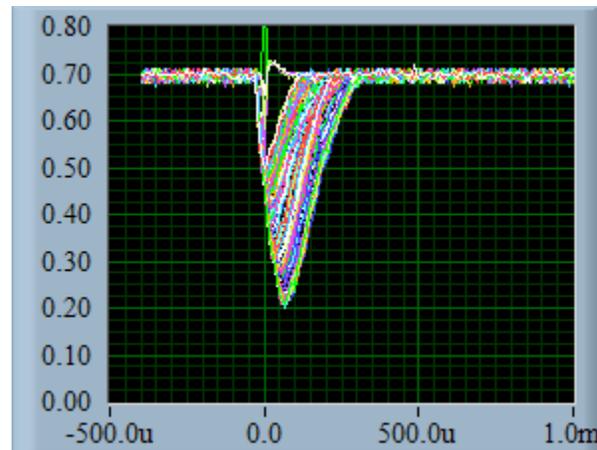
Only Heavy Ions with the highest range induce a transient

Much more negative than positive transients

Preliminary Results Accelerometer - Heavy Ions

Test on temperature sensor: LM20

Negative transients are observed
Broad variation of amplitudes



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Preliminary Results

RF MEMS

Test plan : Number of sample status

Sample repartition as planned in Test plan

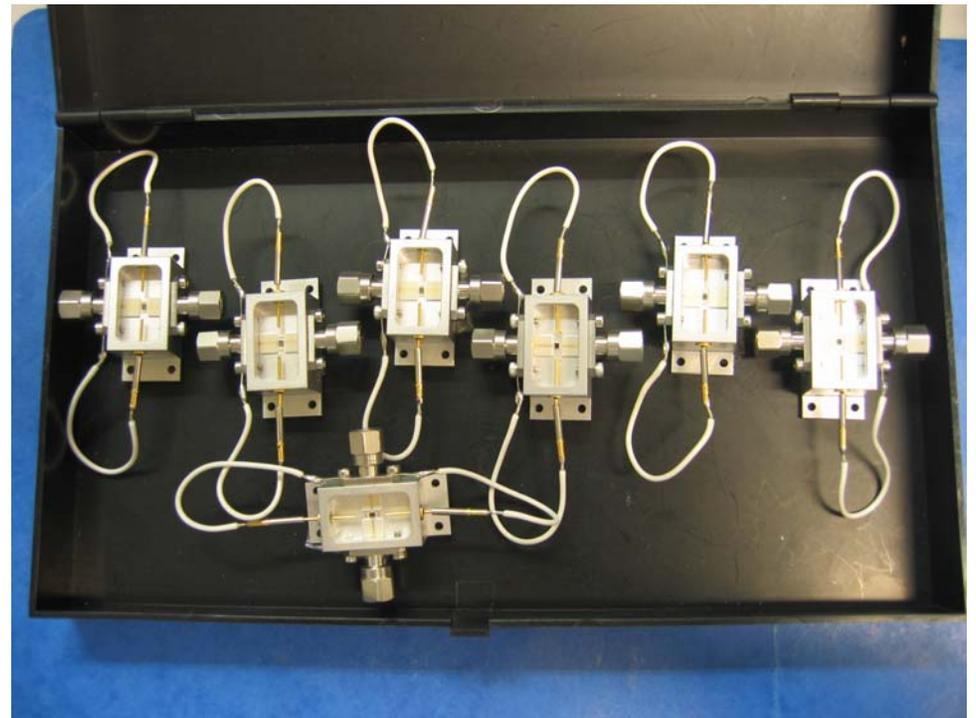
TID LDR		
Conditions	Samples	
1	3	
2	3	
3	3	
4	2	
Ref		2
Total (1) :	11	2

TID HDR		
Conditions	Samples	
x	3	
Total (2) :	3	

Heavy ions tests			
Total :	3	Ref:	2

Protons			
Total (3) :	8	Ref:	2

Total = (1) + (2) + (3) : 25 Samples
Total ref : 2 Samples



Preliminary Results RF MEMS

Focus on : Heavy ions test

- During Heavy Ions test we were looking at the following effects:
 - SET: Single Event Transients
 - Permanent Damage (increase of leakage current)
- SET: If the deposited charge in Si₃N₄ amplified by possible multiplication of charge carriers due to the Electric field
- Permanent Damage: If the heavy ion can modify the structure of the dielectric (thermal spike)

CONCLUSION (1/2)

Preliminary Conclusion on TID & Heavy Ions testing: Accelerometers

- TID : Increase of power supply current starts at 6 – 8 krad
- Heavy Ions:
 - No Latch-up observed
 - SET's observed on acceleration sensing element, temperature sensor
- Next : Deep Analysis on-going with MEMS manufacturer « Colibrys »
 - Protons Testing results
 - TID testing results
 - Heavy Ions

CONCLUSION (2/2)

Preliminary Conclusion on Heavy Ions testing: RF MEMS

- No SET observed
- No significant increase of leakage current
- Pre-radiation and post-radiation measurements:
 - Shift of V_{pin} and V_{pout} by about 5 V on all samples including non irradiated piece. Voltage shift is even larger on non irradiated parts.
 - Heavy ion radiation effects cannot be demonstrated with before/after irradiation measurement comparison.
- Next : Testing with Protons (Analysis on-going) and Dose (gamma) testing